

Surface Mount

Monolithic Amplifier

DC-8 GHz

Product Features

- DC-8 GHz
- Single Voltage Supply
- Internally Matched to 50 Ohm
- Unconditionally Stable
- Low Performance Variation Over Temperature
- Transient Protected
- Protected By US Patent 6,943,629

Typical Applications

- Cellular/ PCS/ 3G Base Station
- CATV, Cable Modem & DBS
- Fixed Wireless & WLAN
- Microwave Radio & Test Equipment



ERA-1SM+

CASE STYLE: WW107

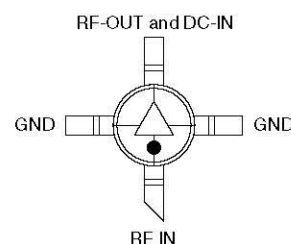
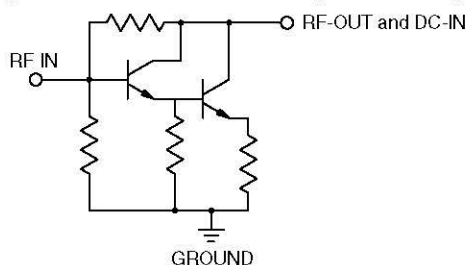
**+ RoHS compliant in accordance
with EU Directive (2002/95/EC)**

The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

General Description

ERA-1SM+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a Micro-X package. ERA-1SM+ uses Darlington configuration and is fabricated using InGaP HBT technology. Expected MTBF is 5,800 years at 85°C case temperature.

simplified schematic and pin description



Function	Pin Number	Description
RF IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.

Mini-Circuits®
ISO 9001 ISO 14001 CERTIFIED

ALL-NEW
minicircuits.com

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For detailed performance specs & shopping online see Mini-Circuits web site



The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

RF/IF MICROWAVE COMPONENTS

REV. L
M106520
ERA-1SM+
061204
Page 1 of 4

Electrical Specifications at 25°C and 40mA, unless noted

Parameter		Min.	Typ.	Max.	Units	Cpk
Frequency Range		DC		6	GHz	
Gain	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz f=4 GHz f=6 GHz f=8 GHz	11.4 10.3	12.3 12.1 11.8 10.9 9.7 7.9 8.2	12.9 12.9	dB	≥ 1.5
Magnitude of Gain Variation versus Temperature (values are negative)	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz f=4 GHz f=6 GHz f=8 GHz		.0012 .0015 .0017 .002 .002 .0022 .0019	.0025 .003 .0035 .004 .004 .005 .005	dB/°C	
Input Return Loss	f=0.1 GHz f=2 GHz f=3 GHz f=4 GHz f=6 GHz f=8 GHz		30 25 23 23 18 16		dB	
Output Return Loss	f=0.1 GHz f=2 GHz f=3 GHz f=4 GHz f=6 GHz f=8 GHz		26 21 16 15 15 15		dB	
Reverse Isolation	f=2 GHz	14	17		dB	
Output Power @ 1 dB compression	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz f=4 GHz f=6 GHz f=8 GHz	10	12 12 12 12 10.5 8		dBm	≥ 1.33
Saturated Output Power (at 3dB compression)	f=0.1 GHz f=2 GHz f=4 GHz f=6 GHz f=8 GHz		13 13 12.5 11 10		dBm	
Output IP3	f=0.1 GHz f=1 GHz f=2 GHz f=4 GHz	24 24 23 20	28 28 28 25		dBm	≥ 1.33
Noise Figure	f=0.1 GHz f=2 GHz f=4 GHz f=6 GHz f=8 GHz		4.3 4.3 4.5 4.9 5.5	5 5.3 5.5	dB	≥ 1.33
Group Delay	f=2 GHz		70		psec	
Recommended Device Operating Current			40		mA	
Device Operating Voltage		3.2	3.4	3.6	V	≥ 1.5
Device Voltage Variation vs. Temperature at 40mA			-2.0		mV/°C	
Device Voltage Variation vs. Current at 25°C			9.4		mV/mA	
Thermal Resistance, junction-to-case ¹			183		°C/W	

Absolute Maximum Ratings

Parameter	Ratings
Operating Temperature*	-45°C to 85°C
Storage Temperature	-65°C to 150°C
Operating Current	75mA
Power Dissipation	330mW
Input Power	15dBm

Note: Permanent damage may occur if any of these limits are exceeded.
These ratings are not intended for continuous normal operation.
¹Case is defined as ground leads.

*Based on typical case temperature rise 5°C above ambient.



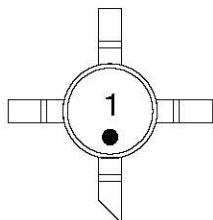
P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For detailed performance specs & shopping online see Mini-Circuits web site



The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

RF/IF MICROWAVE COMPONENTS

Product Marking



Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: WW107

Plastic micro-x, .085 body diameter, lead finish: tin/silver/nickel

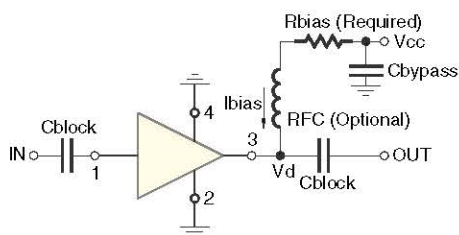
Tape & Reel: F4

Suggested Layout for PCB Design: PL-075

Evaluation Board: TB-408-1+

Environmental Ratings: ENV08T2

Recommended Application Circuit



Test Board includes case, connectors, and components (in bold) soldered to PCB

R BIAS	
Vcc	"1%" Res. Values (ohms) for Optimum Biasing
7	90.9
8	113
9	137
10	162
11	187
12	215
13	237
14	261
15	287
16	309
17	332
18	357
19	383
20	412

ESD Rating

Human Body Model (HBM): Class 1B (500 v to < 1,000 v) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (< 100 v) in accordance with ESD STM 5.2 - 1999

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	J-Std-020C (Jedec Standard)	45 units
4	Moisture Sensitivity Level 1	Bake at 125°C for 24 hours Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-Std-020C (Jedec Standard)	45 units

MSL Test Flow Chart
